

$0.45-\Omega$ CMOS, 1.65-V to 3.6-V, Dual DPDT Analog Switch

FEATURES

- Low Voltage Operation (1.65 V to 3.6 V)
- Low On-Resistance $r_{ON:}$ 0.45 Ω @ 2.7 V
- Fast Switching: $t_{ON} = 28 \text{ ns}$ $t_{OFF} = 17 \text{ ns}$
- QFN-16 (3x3) Package

BENEFITS

- Reduced Power Consumption
- High Accuracy
- Reduce Board Space
- TTL/1.8-V Logic Compatible
- High Bandwidth

APPLICATIONS

- Cellular Phones
- Speaker Headset Switching
- Audio and Video Signal Routing
- PCMCIA Cards
- Battery Operated Systems

DESCRIPTION

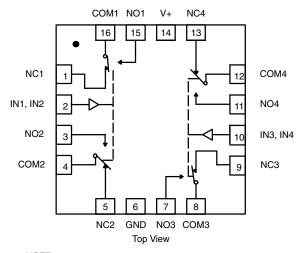
The DG2718 is a dual double-pole/double-throw monolithic CMOS analog switch designed for high performance switching of analog signals. Combining low power, high speed, low on-resistance and small physical size, the DG2718 is ideal for portable and battery powered applications requiring high performance and efficient use of board space.

The DG2718 is built on Vishay Siliconix's low voltage process. An epitaxial layer prevents latchup. Break-before-make is guaranteed.

The switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

DG2718 QFN-16 (3 X 3)



NO	т	F	•

Underside exposed pad has no device electrical connection. It is recommended that no electrical connection is made to it.

TRUTH TABLE					
Logic	NC1, 2, 3 and 4	NO1, 2, 3 and 4			
0	ON	OFF			
1	OFF	ON			

ORDERING INFORMATION*				
Temp Range	Package	Part Number		
-40 to 85°C	16-Pin QFN (3 x 3 mm) Variation 2	DG2718DN-T1-E4		
* Lead-Free Version Available				

Vishay Siliconix

New Product



ABSOLUTE MAXIMUM RATINGS

Reference to GND	
V+	0.3 to +4.0 V
IN, COM, NC, NO ^a	0.3 to (V+ + 0.3 V)
Current (Any terminal except NO, NC or COM) $$.	30 mA
Continuous Current (NO, NC, or COM)	± 300 mA
Peak Current	± 500 mA
(Pulsed at 1 ms, 10% duty cycle)	
Storage Temperature (D Suffix)	65 to 150°C
Package Solder Reflow Conditions ^d	
16-Pin QFN (3 x 3 mm)	250°C
Power Dissipation (Packages) ^b	

Notes:

- Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC Board.
- c. Derate 17.3 mW/°C above 70°C
- d. Manual soldering with iron is not recommended for leadless components. The QFN is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

		Test Conditions Otherwise Unless Specified V+ = 1.8 V, V _{IN} = 0.4 or 1.1 Ve		Limits -40 to 85°C			
Parameter	Symbol		Tempa	Minb	Typc	Max ^b	Unit
Analog Switch							
Analog Signal Range ^d	V _{NO} , V _{NC} , V _{COM}		Full	0		V+	V
On-Resistance ^d	r _{ON}	$V+ = 1.8 \text{ V}, V_{COM} = 0.2 \text{ V}/0.9 \text{ V}, I_{NO}, I_{NC} = 100 \text{ mA}$	Room Full		0.7	2.0 2.8	Ω
Digital Control							
Input High Voltage	V _{INH}		Full	1.1			
Input Low Voltage	V _{INL}		Full			0.4	V
Input Capacitance	C _{in}		Full		6		pF
Input Current	I _{INL} or I _{INH}	V _{IN} = 0 or V+	Full	-1		1	μΑ
Dynamic Characteristic	s		•				
Turn-On Time	t _{ON}	V_{NO} or V_{NC} = 1.5 V, R_L = 50 Ω , C_L = 35 pF	Room Full		62	94 92	
Turn-Off Time	tOFF		Room Full		24	52 55	ns
Break-Before-Make Time	t _d		Full	16			
Charge Injection ^d	Q _{INJ}	C_L = 1 nF, V_{GEN} = 0 V, R_{GEN} = 0 Ω	Room		65		рС
Off-Isolation ^d	OIRR	5	Room		-74		-10
Crosstalkd	X _{TALK}	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 100 kHz$	Room		-74		dB
N. N. 0# 0	C _{NO(off)}	V _{IN} = 0 or V+, f = 1 MHz	Room		108		
N _O , N _C Off Capacitance ^d	C _{NC(off)}		Room		108		
Channel-On Capacitanced	C _{NO(on)}		Room		225		pF
	C _{NC(on)}		Room		225		
Power Supply	•					•	
Power Supply Current	I+	V _{IN} = 0 or V+	Full	i	1	1.0	μА



Vishay Siliconix

SPECIFICATIONS (V+ = 3 V)						
		Test Conditions Otherwise Unless Specified V+ = 3 V, \pm 10%, V _{IN} = 0.5 or 1.4 V ^e		Limits -40 to 85°C			
Parameter	Symbol		Tempa	Minb	Typc	Max ^b	Unit
Analog Switch	•		•		•		
Analog Signal Range ^d	V_{NO}, V_{NC}, V_{COM}		Full	0		V+	V
On-Resistance ^d	r _{ON}	$V+ = 2.7 \text{ V}, V_{COM} = 0.2 \text{ V}/1.5 \text{ V}, I_{NO}, I_{NC} = 100 \text{ mA}$	Room Full		0.45	0.6 0.7	
r _{ON} Flatness ^d	r _{ON} Flatness	V+ = 2.7 V	Room		0.1	0.15	Ω
r _{ON} Match ^d	Δr _{ON}	$V_{COM} = 0$ to V+, I_{NO} , $I_{NC} = 100$ mA	Room		0.05		
Switch Off Leakage Current	I _{NO(off)} , I _{NC(off)}	V+ = 3.3 V, V _{NO} , V _{NC} = 0.3 V/3 V	Room Full	-1 -10		1 10	
Switch on Ecanage Garrent	I _{COM(off)}	V _{COM} = 3 V/0.3 V	Room Full	-1 -10		1 10	nA
Channel-On Leakage Current	I _{COM(on)}	$V+ = 3.3 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 0.3 \text{ V/3 V}$	Room Full	-1 -10		1 10	
Digital Control							
Input High Voltage	V _{INH}		Full	1.4			
Input Low Voltage	V _{INL}		Full			0.5	V
Input Capacitance	C _{in}		Full		6		pF
Input Current	I _{INL} or I _{INH}	V _{IN} = 0 or V+	Full	-1		1	μΑ
Dynamic Characteristics	3						
Turn-On Time	t _{ON}	V_{NO} or V_{NC} = 1.5 V, R_L = 50 Ω , C_L = 35 pF	Room Full		28	57 60	
Turn-Off Time	t _{OFF}		Room Full		17	45 47	ns
Break-Before-Make Time	t _d		Full	1			
Charge Injection ^d	Q _{INJ}	C_L = 1 nF, V_{GEN} = 0 V, R_{GEN} = 0 Ω	Room		232		рC
Off-Isolation ^d	OIRR	$R_1 = 50 \Omega, C_1 = 5 pF, f = 100 kHz$	Room		-75		dB
Crosstalk ^d	X _{TALK}	n _L = 50 ½, C _L = 5 pr, 1 = 100 kn2	Room		-75		uБ
N. N. Off Capacitance	C _{NO(off)}		Room		102		
N _O , N _C Off Capacitance ^d	C _{NC(off)}) V _{IN} = 0 or V+, t = 1 MHz Ro	Room		102		ьE
Channel-On Capacitance ^d	C _{NO(on)}		Room		234		pF
	C _{NC(on)}		Room		234		
Power Supply							
Power Supply Range	V+			2.7		3.3	V
Power Supply Current	I+	V _{IN} = 0 or V+	Full			1.0	μΑ

Notes:

- Res.

 Room = 25°C, Full = as determined by the operating suffix.

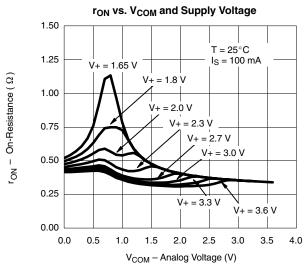
 The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet. Typical values are for design aid only, not guaranteed nor subject to production testing.

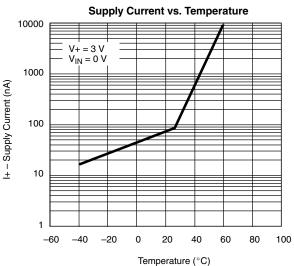
 Guarantee by design, nor subjected to production test.

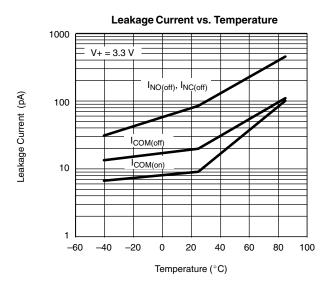
- V_{IN} = input voltage to perform proper function.
 Guaranteed by 5-V leakage testing, not production tested.

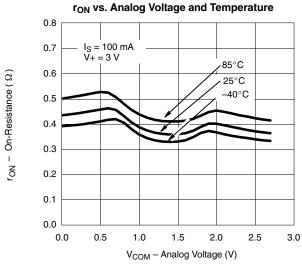


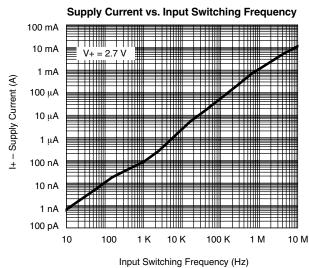
TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

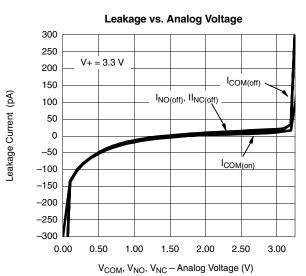












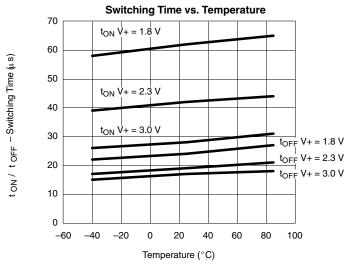


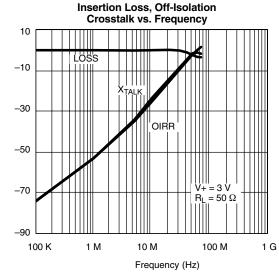


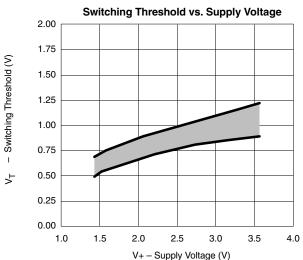
TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

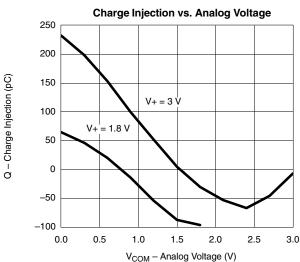
New Product

Loss, OIRR, X_{TALK} (dB)

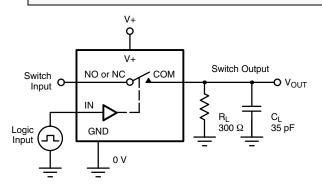








TEST CIRCUITS



C_L (includes fixture and stray capacitance)

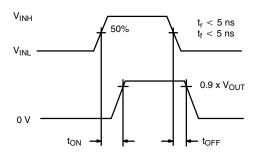
$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$

Figure 1. Switching Time

Logic

Input

Switch Output



Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.



TEST CIRCUITS

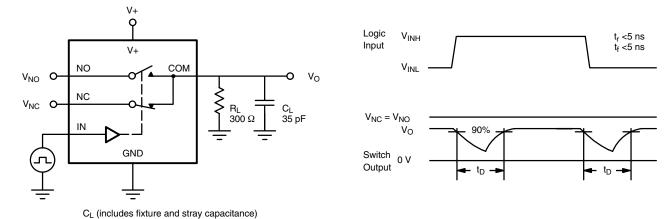


Figure 2. Break-Before-Make Interval

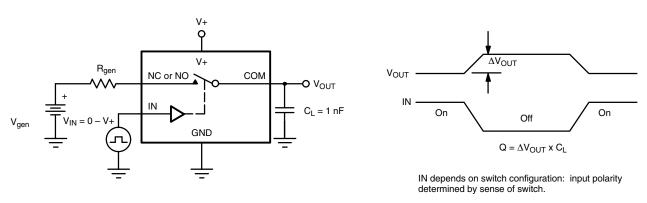


Figure 3. Charge Injection

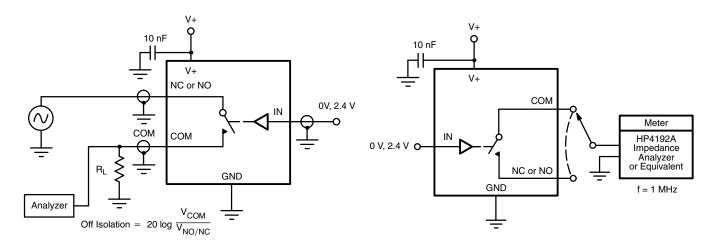


Figure 4. Off-Isolation

Figure 5. Channel Off/On Capacitance



Vishay

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.

Document Number: 91000 Revision: 18-Jul-08

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Vishay:

DG2718DN-T1-E4